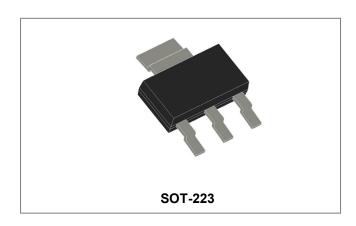






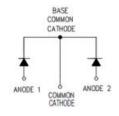
20CJQ100 SCHOTTKY RECTIFIER



Features

- 150 °C T_J operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- "-A" is an AEC-Q101 qualified device
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Redundant power subsystems
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	100	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=126°C, rectangular wave form	1(Per Leg) 2(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse, T _C = 25 °C	26	Α

Electrical Characteristics:

Characteristics	Symbol	ool Condition		Max.	Units
Forward Voltage Drop	V _{F1}	@ 1A, Pulse, T _J = 25 °C	0.80	0.85	V
(Per Leg)*	V_{F2}	@ 1A, Pulse, T _J = 125 °C	0.68	0.75	V
Reverse Current (Per Leg)*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}C$	0.0003	0.5	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	0.2	1.0	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	40	45	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse width < 300 μ s, duty cycle < 2%

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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Lead	$R_{ heta JL}$	DC operation	25	°C/W
Typical Thermal Resistance Junction to Ambient	R ₀ JA	DC operation	65	°C/W
Approximate Weight	wt	-	0.13	g
Case Style	SOT-223			

Ratings and Characteristics Curves

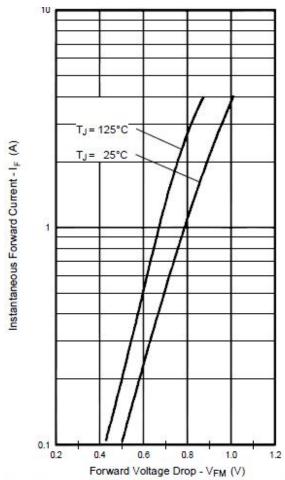


Fig. 1 Typical Forward Voltage Drop Characteristics (Per Leg)

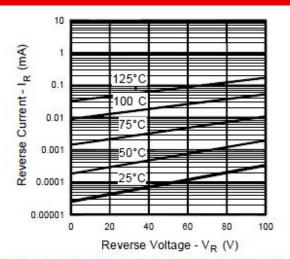


Fig. 2 Typical Values of Reverse Current Vs. Reverse Voltage (Per Leg)

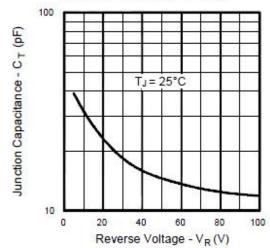


Fig. 3 Typical Junction CapacitanceVs. Reverse Voltage (Per Leg)

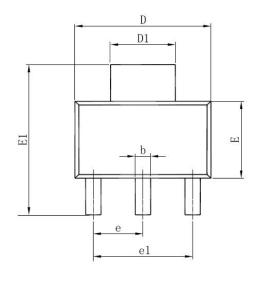
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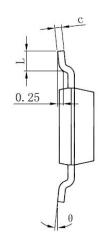






Mechanical Dimensions SOT-223





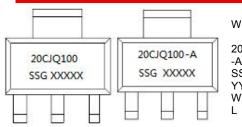
OVMDOL	Millimeters		Inches		
SYMBOL	MIN.	MAX.	MIN.	MAX.	
А	1.520	1.800	0.060	0.071	
A1	0.000	0.100	0.000	0.004	
A2	1.500	1.700	0.059	0.067	
b	0.660	0.820	0.026	0.032	
С	0.250	0.350	0.010	0.014	
D	6.200	6.400	0.244	0.252	
D1	2.900	3.100	0.114	0.122	
E	3.300	3.700	0.130	0.146	
E1	6.830	7.070	0.269	0.278	
е	2.300(BSC)		0.091(BSC)		
e1	4.500	4.700	0.177	0.185	
L	0.900	1.150	0.035	0.045	
θ	0°	10°	0°	10°	

Ordering Information

Device	Package	Shipping
20CJQ100	SOT-223 (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

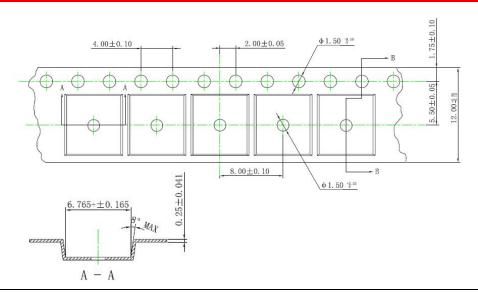


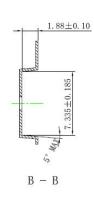
Where XXXXX is YYWWL

20CJQ100 = Part Name -A = AEC-Q101 SSG = SSG

YY = Year WW = Week L = Lot Number

Carrier Tape Specification SOT-223





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